

**IN THE UNITED STATES DISTRICT COURT
FOR THE DISTRICT OF DELAWARE**

ELM 3DS INNOVATIONS, LLC, a)
Delaware limited liability company,)
)
Plaintiff,)

v.)

SAMSUNG ELECTRONICS CO., LTD., a)
Korean business entity,)
SAMSUNG SEMICONDUCTOR, INC., a)
California corporation,)
SAMSUNG ELECTRONICS AMERICA,)
INC., a New York corporation,)
SAMSUNG TELECOMMUNICATIONS)
AMERICA, LLC, a Delaware limited)
liability company, and)
SAMSUNG AUSTIN SEMICONDUCTOR,)
LLC, a Delaware limited liability company,)

Defendants.

C.A. No. _____

Jury Trial Demanded

COMPLAINT FOR PATENT INFRINGEMENT

Plaintiff Elm 3DS Innovations, LLC (“Plaintiff” or “Elm 3DS”), by its attorneys, for its complaint against Defendants Samsung Electronics Co., Ltd., and its U.S. subsidiaries and related entities Samsung Semiconductor, Inc., Samsung Electronics America, Inc., Samsung Telecommunications America, LLC, and Samsung Austin Semiconductor, LLC (individually or collectively “Defendants” or “Samsung”) hereby alleges as follows:

INTRODUCTION

1. This is an action for patent infringement under the Patent Laws of the United States, 35 U.S.C. § 1 et seq., for infringing the following Elm 3DS patents:

- (a) U.S. Patent No. 7,193,239 (“Leedy ’239 patent”), entitled “*Three Dimensional Structure Integrated Circuit*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 1);
- (b) U.S. Patent No. 7,504,732 (“Leedy ’732 patent”), entitled “*Three Dimensional Structure Memory*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 2);
- (c) U.S. Patent No. 8,035,233 (“Leedy ’233 patent”), entitled “*Adjacent Substantially Flexible Substrates Having Integrated Circuits That Are Bonded Together By Non-Polymeric Layer*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 3);
- (d) U.S. Patent No. 8,410,617 (“Leedy ’617 patent”), entitled “*Three Dimensional Structure Memory*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 4);
- (e) U.S. Patent No. 8,629,542 (“Leedy ’542 patent”), entitled “*Three Dimensional Structure Memory*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 5);
- (f) U.S. Patent No. 8,653,672 (“Leedy ’672 patent”), entitled “*Three Dimensional Structure Memory*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 6);
- (g) U.S. Patent No. 8,796,862 (“Leedy ’862 patent”), entitled “*Three Dimensional Structure Memory*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 7);

- (h) U.S. Patent No. 8,824,159 (“Leedy ’159 patent”), entitled “*Three Dimensional Structure Memory*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 8);
- (i) U.S. Patent No. 8,841,778 (“Leedy ’778 patent”), entitled “*Three Dimensional Structure Memory*,” owned by Elm 3DS Innovations, LLC (attached as Ex. 9).

2. The Elm 3DS patents cover foundational semiconductor technologies in the design and manufacture of three-dimensional integrated circuits such as memory, processors, and image sensors. These fundamental technologies reduce manufacturing costs while improving speed and efficiency. Among other things, the Elm 3DS patents disclose technologies that enable semiconductor manufacturers to stack multiple integrated circuits (“die”) on top of one another within one integrated circuit package, and to form interconnect circuitry for communication among the stacked die, including interconnect circuitry passing through silicon substrates in stacked integrated circuits.

3. Samsung has infringed and continues to infringe the Elm 3DS patents, directly and indirectly, by making using, selling, offering for sale, and/or importing into the United States, semiconductor products with multiple stacked die and/or electronics products containing the same; and by encouraging third parties to use, sell, offer for sale, and/or import into the United States, Samsung semiconductor products with multiple stacked die and/or electronics products containing the same, with knowledge of the Elm 3DS patents and in the infringement resulting therefrom.

THE PARTIES

4. Elm 3DS Innovations, LLC, is a Delaware limited liability company with its principal address at 26147 Carmelo Street, Carmel, California 93923. Elm 3DS owns patents, originally issued to its President, inventor Glenn J. Leedy, covering Mr. Leedy's groundbreaking technology for thinning, vertically stacking and interconnecting integrated circuits.

5. Samsung Electronics Co., Ltd. ("SEC") is a Korean business entity that lists its global headquarters as 129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, Republic of Korea. On information and belief, SEC is the global leader in the electronics market, which includes computer memory and consumer electronics products such as mobile phones and tablet computers. On information and belief, SEC is the second largest semiconductor manufacturer in the world, and the leader in DRAM, NAND Flash, solid state drives ("SSDs"), mobile DRAM and graphics memory. On information and belief, SEC designs, manufactures, has manufactured, uses, offers for sale, sells and/or imports into the United States—including into Delaware—billions of dollars of computer memory and consumer electronics each year.

6. Samsung Electronics America, Inc. ("SEA") is a New York corporation that lists its headquarters as 85 Challenger Road, Ridgefield Park, New Jersey 07660. SEA is a wholly-owned subsidiary of SEC. On information and belief, SEA markets, uses, offers for sale, sells and/or imports into the United States—including into Delaware—various electronics products including, plasma TVs and cameras; computer monitors, laser printers and solid state drives; and handheld wireless smartphones.

7. Samsung Semiconductor, Inc. (“SSI”) is a California corporation that lists its headquarters as 3655 North First Street, San Jose, California 95134. SSI is a wholly-owned subsidiary of SEC. On information and belief, SSI manufactures, has manufactured, uses, offers for sale, sells and/or imports into the United States – including into Delaware – various semiconductor products including DRAM, NAND Flash, SSDs, mobile DRAM, graphics memory, and system logic.

8. Samsung Telecommunications America, LLC (“STA”) is a Delaware limited liability company that lists its headquarters as 1301 East Lookout Drive, Richardson, Texas 75082. STA is a wholly-owned subsidiary of SEC and SEA. On information and belief, STA markets, sells, or offers for sale, and/or imports into the United States – including into Delaware – a variety of personal and business communication devices, including mobile phones and tablet computers.

9. Samsung Austin Semiconductor, LLC (“SAS”) is a Delaware limited liability company that lists its headquarters as 12100 Samsung Boulevard, Austin, TX 78754. On information and belief, SAS operates as a subsidiary of SSI. On information and belief, SAS operates a semiconductor fabrication plant in Austin, TX, where it manufactures, has manufactured, uses, offers for sale, sells and/or imports into the United States – including into Delaware – NAND flash memory and system logic.

JURISDICTION

10. This is an action for patent infringement, over which this Court has subject matter jurisdiction pursuant to 28 U.S.C. §§ 1331 and 1338(a).

11. This Court has personal jurisdiction over each of the Defendants consistent with the requirements of the Due Process Clause of the United States Constitution and the Delaware Long Arm Statute. On information and belief, each Defendant transacts substantial business in Delaware, and/or has committed and continues to commit acts of patent infringement in Delaware as alleged in this Complaint. In addition, Samsung Telecommunications America, LLC and Samsung Austin Semiconductor, LLC are incorporated under the laws of Delaware. Further, on information and belief, the Defendants have admitted or not contested proper personal jurisdiction in this District in other patent infringement actions.

VENUE

12. Venue is proper in this District pursuant to 28 U.S.C. §§ 1391 (b)-(d) and 1400(b) because Defendants are subject to personal jurisdiction in this District, each has committed acts of patent infringement in this District, each has purposefully availed itself of the rights and benefits of Delaware law and regularly does and solicits business in Delaware, and each derives substantial revenue from things used or consumed in this District. Further, on information and belief, the Defendants have admitted or not contested proper venue in this District in other patent infringement actions.

FACTUAL BACKGROUND

I. The Elm 3DS Patents

13. Plaintiff solely owns all rights, titles, and interests in and to the following United States patents (collectively, the “Elm 3DS Patents”), including the exclusive rights to bring suit with respect to any past, present, and future infringement thereof:

- (a) U.S. Patent No. 7,193,239 (“Leedy ’239 patent”), entitled “*Three Dimensional Structure Integrated Circuit*,” which was duly and legally issued on March 20, 2007, from a patent application filed July 3, 2003, with Glenn J. Leedy as the named inventor. The Leedy ’239 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;
- (b) U.S. Patent No. 7,504,732 (“Leedy ’732 patent”), entitled “*Three Dimensional Structure Memory*,” which was duly and legally issued on March 17, 2009, from a patent application filed August 19, 2002, with Glenn J. Leedy as the named inventor. The Leedy ’732 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;
- (c) U.S. Patent No. 8,035,233 (“Leedy ’233 patent”), entitled “*Adjacent Substantially Flexible Substrates Having Integrated Circuits That Are Bonded Together By Non-Polymeric Layer*,” which was duly and legally issued on October 11, 2011, from a patent application filed March 3, 2003, with Glenn J. Leedy as the named inventor. The Leedy ’233 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;

- (d) U.S. Patent No. 8,410,617 (“Leedy ’617 patent”), entitled “*Three Dimensional Structure Memory*,” which was duly and legally issued on April 2, 2013, from a patent application filed July 4, 2009, with Glenn J. Leedy as the named inventor. The Leedy ’617 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;
- (e) U.S. Patent No. 8,629,542 (“Leedy ’542 patent”), entitled “*Three Dimensional Structure Memory*,” which was duly and legally issued on January 14, 2014, from a patent application filed March 17, 2009, with Glenn J. Leedy as the named inventor. The Leedy ’542 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;
- (f) U.S. Patent No. 8,653,672 (“Leedy ’672 patent”), entitled “*Three Dimensional Structure Memory*,” which was duly and legally issued on February 18, 2014, from a patent application filed May 27, 2010, with Glenn J. Leedy as the named inventor. The Leedy ’672 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;

- (g) U.S. Patent No. 8,796,862 (“Leedy ’862 patent”), entitled “*Three Dimensional Structure Memory*,” which was duly and legally issued on August 5, 2014, from a patent application filed August 9, 2013, with Glenn J. Leedy as the named inventor. The Leedy ’862 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;
- (h) U.S. Patent No. 8,824,159 (“Leedy ’159 patent”), entitled “*Three Dimensional Structure Memory*,” which was duly and legally issued on September 2, 2014, from a patent application filed March 31, 2009, with Glenn J. Leedy as the named inventor. The Leedy ’159 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor;
- (i) U.S. Patent No. 8,841,778 (“Leedy ’778 patent”), entitled “*Three Dimensional Structure Memory*,” which was duly and legally issued on September 23, 2014, from a patent application filed August 9, 2013, with Glenn J. Leedy as the named inventor. The Leedy ’778 patent claims priority from U.S. Patent No. 5,915,167, which was duly and legally issued on June 22, 1999, from a patent application filed on April 4, 1997, with Glenn J. Leedy as the named inventor.

Each of the Elm 3DS Patents is valid and enforceable.

14. The Elm 3DS Patents disclose three-dimensional integrated circuit structures and methods for manufacturing the same. In one exemplary embodiment, the patents disclose a three-dimensional structure with thinned and polished integrated circuit substrates that are stacked on top of one another and electrically connected. The disclosed technology enhances memory speed and efficiency because the signal paths are shorter. The disclosed technology also improves memory density because multiple storage arrays can be stacked within a single package that meets industry form-factor requirements. Industry implementations are referred to as “stacked” memories that are electrically connected with either wire bonds or through-silicon vias (“TSV”).

II. The Inventor

15. Glenn J. Leedy is the sole named inventor on the Elm 3DS Patents. Mr. Leedy has been involved in the information technology industry since the 1960s. Working first for established IT companies such as IBM and Fairchild Semiconductor, and eventually as an independent inventor, Mr. Leedy has consistently developed essential technologies that have significantly advanced the state of the art. Today, Mr. Leedy’s foundational inventions are used in literally billions of semiconductor products around the world.

16. Mr. Leedy graduated from the University of Michigan with a degree in Mathematics, in 1968.

17. After working at IBM, the University of Michigan, Sycor and ComShare, Mr. Leedy joined Digital Equipment Corporation (“DEC”) in 1976. While there, Mr. Leedy assisted in the design of DEC’s first 32-bit minicomputer, and in the development

of the first 16-bit microprocessor. Mr. Leedy also invented a solution for providing high-speed backup and restore for large databases, an advance in the technology that saved DEC and its customers millions of dollars.

18. Mr. Leedy joined Fairchild Semiconductor in 1978. While there, Mr. Leedy assisted in the development of gate-array programmable logic products. Mr. Leedy's time at Fairchild also provided him with the opportunity to become familiar with the semiconductor fabrication processes used to manufacture the integrated circuits he helped design.

19. In 1981, Mr. Leedy joined National Semiconductor. While there, Mr. Leedy assisted in the development of the computer industry's first 32-bit microprocessor.

20. In 1983, Mr. Leedy left National Semiconductor to start his own business: American Information Systems ("AIS"). Mr. Leedy formed his own business to continue inventing but with independent creative control and ownership of his inventions.

21. Under Mr. Leedy's direction, AIS developed and sold a 32-bit minicomputer. The minicomputer used the 32-bit National Semiconductor microprocessor Mr. Leedy had helped develop, and the minicomputer was instantly popular because it cost a fraction of the 32-bit DEC minicomputer Mr. Leedy worked on for his prior employer. AIS was short-lived, however, as National Semiconductor decided to cease manufacture and development of its 32-bit microprocessor. Without

an affordable alternative 32-bit processor on the market, AIS' cost-performance advantage disappeared and it was forced to shut down.

22. After AIS, Mr. Leedy worked for General Research for several years before again going into business for himself in 1989. Mr. Leedy then devoted himself to finding solutions to the various technological challenges he had encountered during his two decades in the IT industry. Over the next few years, Mr. Leedy developed the technologies underlying two patent portfolios that disclose and claim foundational inventions found in modern semiconductors the world over.

23. In the early 1990s, Mr. Leedy applied for and received a portfolio of patents built around his Membrane Dielectric Isolation ("MDI") technology. The MDI technology uses a thin, flexible membrane of dielectric material to electrically isolate semiconductor devices such as transistors, which can then be used to form test circuitry.

24. Mr. Leedy developed the MDI technology in an effort to develop a semiconductor-grade dielectric that could serve as a membrane for testing bare integrated circuits. Mr. Leedy first worked on integrated circuit fabrication equipment in the basement of a friend, and later with an integrated circuit equipment manufacturer. One key aspect of the MDI technology was Mr. Leedy's development of a tensile low-stress dielectric that could be fabricated into a flexible, free-standing membrane. The ductile characteristics of the novel membrane permitted "at speed" testing of integrated circuits while in wafer form.

25. Mr. Leedy's MDI technology enabled testing methods and devices that ultimately became essential components in the semiconductor manufacturing process, a

fact validated by Mr. Leedy's sale of the MDI patent portfolio in 2008 to Taiwan Semiconductor Manufacturing Co., the world's largest semiconductor foundry.

26. Following the successful development of his MDI technology, Mr. Leedy next applied for and received a portfolio of patents built around his Three-Dimensional Stacked "3DS" integrated circuit technology. The 3DS technology uses thinned, polished, flexible substrates to form vertical stacks of integrated circuits that are connected to one another using either wire-bonds, or vertical interconnects that pass through the stacked substrates.

27. Mr. Leedy developed the 3DS technology in an effort to solve the processor-memory bottleneck – a longstanding barrier in computer-system design. The bottleneck arises when a computer's processor is able to request and process data faster than the memory is able to provide it. Mr. Leedy believed that building the memory vertically, by stacking memory circuits on top of each other, rather than laying the memory circuits out horizontally, would shorten the electrical paths used to read and write data, thereby improving memory read/write speeds. Mr. Leedy was the first to understand that, in order to obtain an acceptable yield when stacking and connecting multiple thinned and polished integrated circuits, one needed to use a tensile low-stress dielectric layer to retain the structural integrity of the thinned and polished substrates. This prevented the substrates from cracking or warping, which can cause "bad" die.

28. Mr. Leedy maintains control over the Elm 3DS portfolio to this day, as Elm 3DS's President, and has been extremely active in its development. In preparing the 3DS technology for patenting, Mr. Leedy drafted a rich specification that provides –

among other things – a detailed account of the technical aspects of his inventions, the benefits associated with the inventions, and various embodiments of the inventions. The disclosures in the specification have provided enormous benefit to the semiconductor industry, and have also permitted Mr. Leedy to claim the technical aspects of his inventions across the portfolio in many different ways that the semiconductor industry can understand. He continues to prosecute a number of patent applications that arise from his groundbreaking inventions.

29. Mr. Leedy's 3DS technology has allowed semiconductor manufacturers to improve performance and to lower the "cost-per-bit" of memory storage. Using thin integrated circuits allows manufacturers to stack multiple integrated circuits in a single industry-standard package with a thickness of 1.2 mm, a feature demanded by form-factor sensitive industries such as servers and smartphones. Further, using vertical interconnects improves memory speed, reduces power consumption, and shrinks the integrated circuit footprint.

30. Presently, all three leading memory manufacturers – Samsung, SK Hynix and Micron – use Mr. Leedy's 3DS technology in various stacked semiconductor products. And in the future the industry's adoption of Mr. Leedy's 3DS technology will become more widespread, as the cost of propagating Moore's Law and fitting more and more transistors on a single silicon die becomes increasingly cost-prohibitive.

31. In 2006, the transistor design node used to fabricate leading microprocessors was 65 nm. Today, the transistor design node used to fabricate leading microprocessors is 22 nm. According to one industry report, constructing a

semiconductor fabrication facility at the 65 nm transistor design node cost under \$3 billion, and designing a chip for fabrication on the 65 nm node cost under \$50 million. http://www.eetimes.com/author.asp?section_id=36&doc_id=1323755 (last accessed Nov. 20, 2014) (attached as Ex. 10.) According to the same report, constructing a semiconductor fabrication facility at the 22 nm node cost nearly \$9 billion, and designing a chip for fabrication on the 22 nm node cost nearly \$150 million.

32. Mr. Leedy's 3DS technology provides the solution to the compounding cost of semiconductor fabrication at smaller transistor nodes, by providing semiconductor manufacturers with the technologies needed to continue delivering faster, denser, and more efficient memories – it allows the manufacturers to expand memory up rather than out. The manufacturers' adoption of this technology can be seen in their development of technologies such stacked NAND flash, the Hybrid Memory Cube ("HMC"), and TSV.

III. The Meeting With Defendants

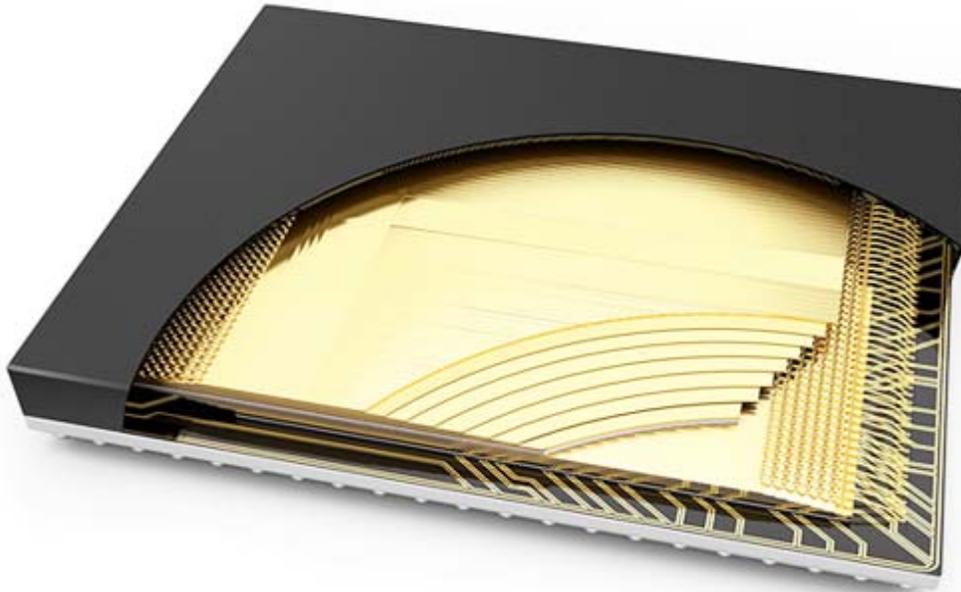
33. Mr. Leedy personally met with Samsung in 2000 or 2001, shortly after issuance of the '167 patent, the first in the 3DS family of patents, in 1999. During the meeting, Mr. Leedy provided Samsung with a slide presentation and a copy of the '167 patent, and explained the benefits of the patented technology. Mr. Leedy also explained that the technology was available to a limited number of licensees. Terms were not discussed, and a license agreement was never reached.

IV. The Defendants' Direct Infringement

34. Despite not having a license to Mr. Leedy's 3DS technology, Defendants have widely used it in their stacked memory products. Evidence of Defendants' infringement can be found on their website, at www.samsung.com, where Defendants describe their stacked semiconductor products.

35. According to Samsung's website, it uses "High-density Packaging Technology for Flash memory products, which stacks individual memory chips on top of one another within a single package with a low-profile, enabling the production of flash memory devices with the highest densities and storage capacities." Samsung further states that "Internally, the die stack design for the flash memory stack [sic] is critical factors[sic] to determine the packaging yield, its reliability of products, and its form factor." See <http://www.samsung.com/global/business/semiconductor/support/package-info/package-datasheet/flash> (last accessed Nov. 20, 2014) (attached as Ex. 11.)

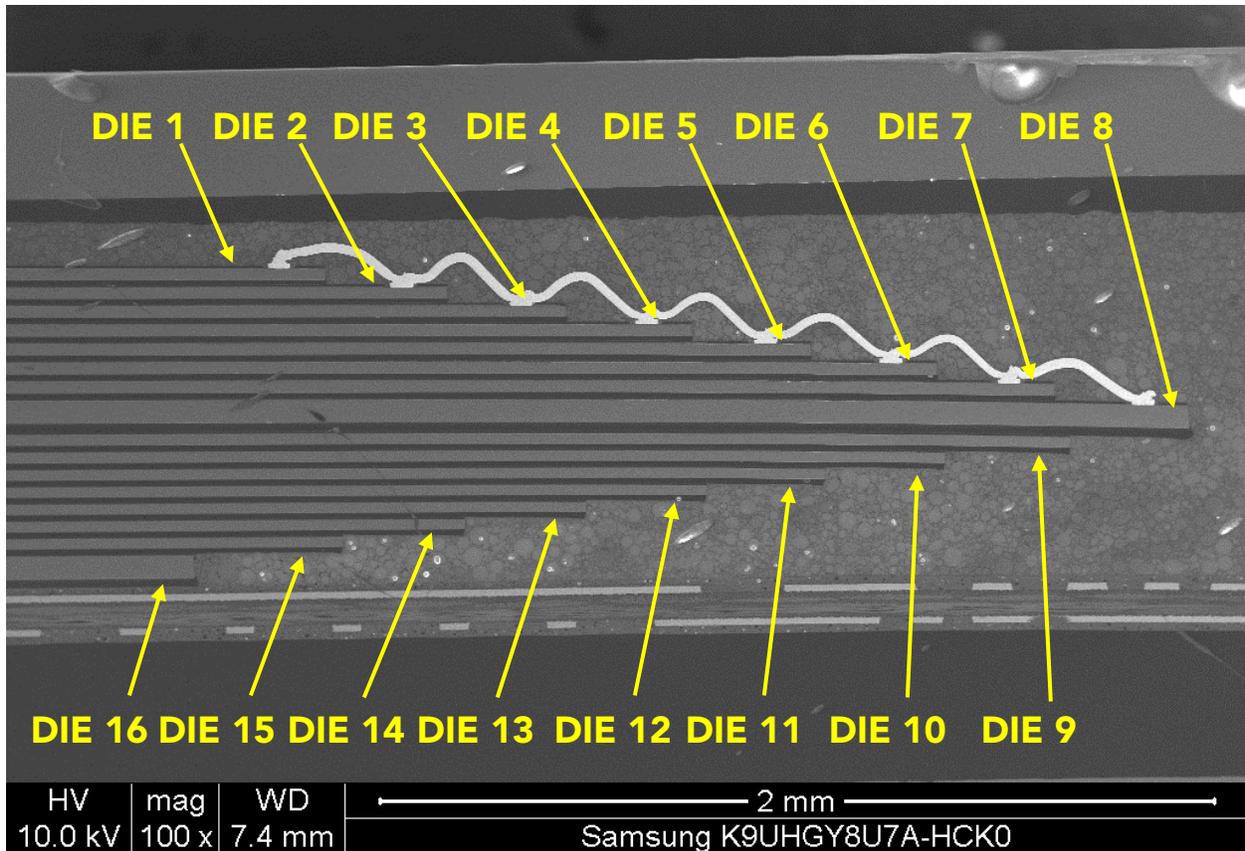
36. Samsung's website represents that the "The immediate advantage of this [die-stacking] approach is a significant saving in the total area occupied by the memory device. The die stack design is thus extensively used in flash memory for applications where space is severely restricted, such as mobile handsets, SSDs, and memory cards, among others." This technology "is resulting in faster and higher capacity nonvolatile storage devices, such as solid state drives." See Ex. 11. Samsung provides the following image of its die-stack design:



37. According to Samsung, the die-stacking technology allows it to provide the following benefits:

- Ultra-high memory densities – Samsung flash memory is the highest density flash memory across the electronics and semiconductor segment. Samsung supplies 128 GB flash memory devices internally organized as 16-stack MCP flash memory, with 64 Gb per die.
- Lowest footprints and thinnest profiles – Samsung provides the smallest packages for all types of flash memory. Samsung’s processes make it easier to deploy the memory device in space-constrained applications such as SSD modules of notebooks, tablets and mobile handsets.

38. An example of Samsung’s die-stacking technology in Flash NAND memory is shown below:



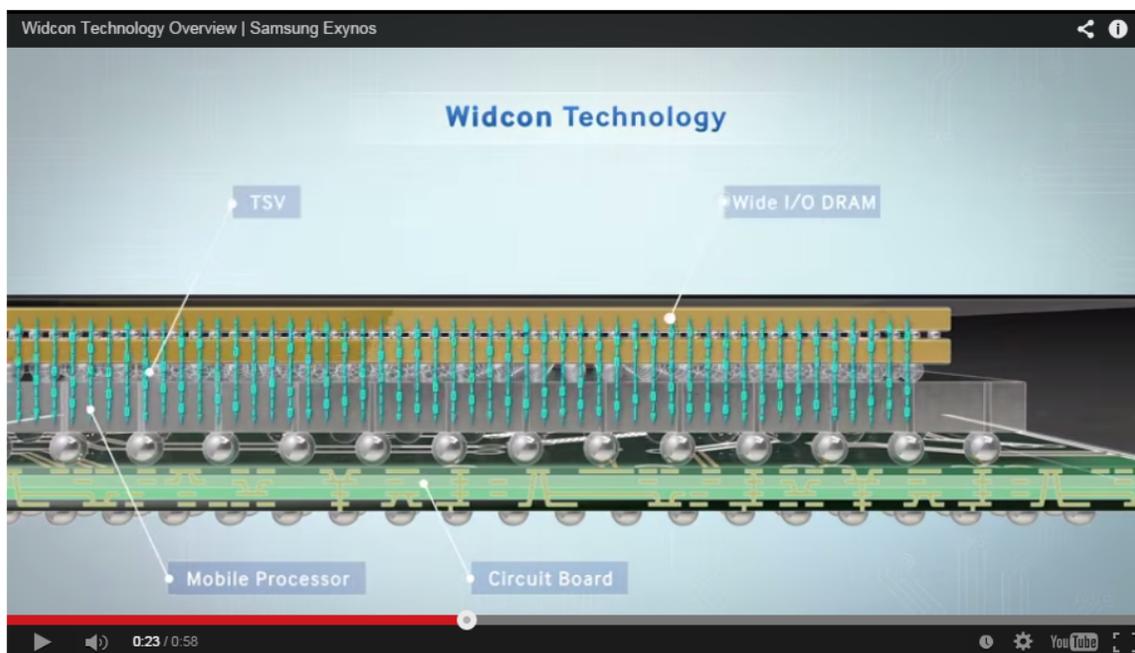
39. Samsung's website also describes its 3D V-NAND technology, which, in addition to stacking die vertically, stacks memory cells vertically. See <http://www.samsung.com/global/business/semiconductor/html/product/flash-solution/vnand/overview.html> (last accessed Nov. 20, 2014) (attached as Ex. 12.) On information and belief, Samsung offers 3D V-NAND in 2-stack, 4-stack, 8-stack and 16-stack configurations.

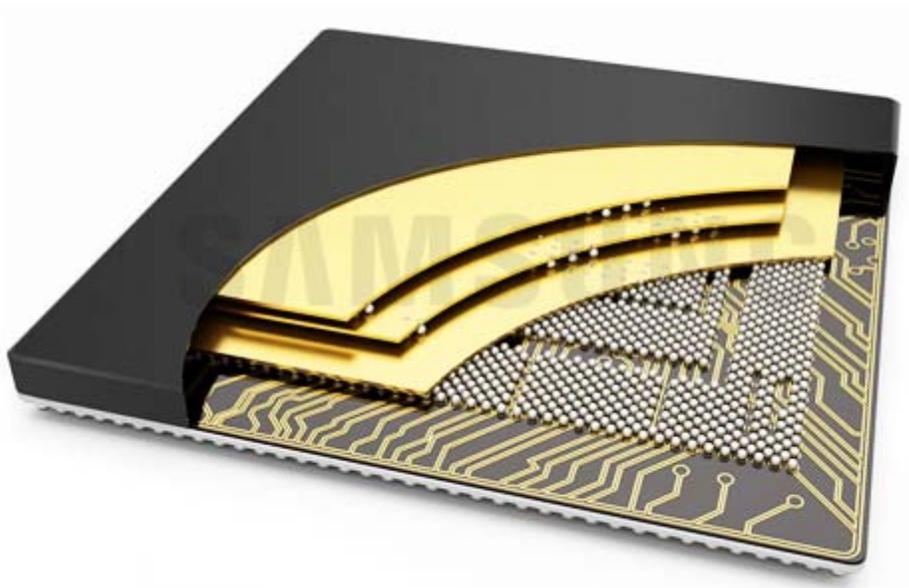
40. Samsung's website also discusses stacked memories in the context of its DRAM products. According to Samsung, the Flip Chip technology used in its DRAM packages means the products are suitable for future packaging technologies such as TSV. <http://www.samsung.com/global/business/semiconductor/support/package-info/package-datasheet/dram> (last accessed Nov. 20, 2014) (attached as Ex. 13.)

41. Samsung has represented that it is using TSV technology in its Wide IO Memory Solutions. According to a presentation, Samsung stated that it was applying 3D TSV to Logic and Wide IO Memory. http://www.samsung.com/us/business/oem-solutions/pdfs/Web_DAC2012_TSV_demo-ah.pdf (last accessed Nov. 20, 2014) (attached as Ex. 14.)

42. One example of Samsung's use of Wide IO technology with TSV – marketed as Widcon – is its Exynos 5 Octa processor. Samsung states that TSV provides better energy efficiency, higher bandwidth, maximum performance even at low clock speeds, and superior thermal dissipation for full performance at low power. http://www.samsung.com/global/business/semiconductor/minisite/Exynos/w/solution.html?v=octa_widcon (last accessed Nov. 20, 2014) (attached as Ex. 15.)

43. Samsung's website provides the following illustrations and videos describing the Widcon technology in its Exynos Octa processors:





<http://www.samsung.com/global/business/semiconductor/support/package-info/package-datasheet/application-processor> (last accessed Nov. 20, 2014) (attached as Ex. 16.)

44. Samsung has also represented that it is using TSV technology in some of its new DDR4 DRAM memory modules. According to a press release, “To build a 3D TSV DRAM package, the DDR4 dies are ground down as thin as a few dozen micrometers, then pierced to contain hundreds of fine holes. They are vertically connected through electrodes that are passed through the holes. As a result, the new 64GB TSV module performs twice as fast as a 64GB module that uses wire bonding packaging, while consuming approximately half the power.” <http://www.samsung.com/global/business/semiconductor/news-events/press-releases/detail?newsId=13602> (last accessed Nov. 20, 2014) (attached as Ex. 17.)

45. Further, “Samsung, has worked on improving 3D TSV technology since it developed 40nm-class 8GB DRAM RDIMMs in 2010 and 30nm-class 32GB DRAM RDIMMs in 2011 using 3D TSV. This year, Samsung started operating a new manufacturing system dedicated to TSV packaging, for mass producing the new server modules.” *See id.*

46. Samsung has actual notice of all of the Elm 3DS Patents and the infringement alleged herein at least upon filing of this Complaint (if not earlier), pursuant to 35 U.S.C. § 287(a).

47. Samsung has directly infringed, and continues to infringe, literally or under the doctrine of equivalents, one or more claims of the Elm 3DS Patents by acting without authority to make, have made, use, offer to sell, sell within the United States, and/or import into the United States, semiconductor products that practice the claimed inventions, and/or electronics products that incorporate said semiconductor products, including *inter alia* smartphones and solid state drives (“SSD”).

48. The above-described acts of infringement committed by Defendants have caused injury and damage to Plaintiff, and will cause additional severe and irreparable injury and damages in the future.

V. The Defendant’s Indirect Infringement.

GENERAL ALLEGATIONS

49. Samsung indirectly infringes the Elm 3DS Patents by inducing infringement by others, such as OEMs, manufacturers, importers, resellers, customers and end users under 35 U.S.C. § 271(b) in this District and elsewhere in the United

States. On information and belief, Samsung has intended and continues to intend to induce patent infringement by these third parties and has had actual knowledge that the inducing acts would cause infringement or has been willfully blind to the possibility that its inducing acts would cause infringement. For example, Samsung is aware that the structural aspects of thinned, stacked, and electrically interconnected semiconductors are always present in infringing stacked semiconductor packages and cannot be modified by a purchaser of such stacked semiconductor packages and, therefore, that Samsung's customers will infringe one or more claims of the Elm 3DS Patents by incorporating such stacked semiconductor packages in other products, and that subsequent sales of such products would be a direct infringement of one or more claims of the Elm 3DS Patents.

50. On information and belief, Samsung indirectly infringes one or more claims of the Elm 3DS Patents by inducing numerous third-party OEMs, manufacturers, importers, resellers, customers, and end users to make, have made, use, sell, offer to sell in, and/or import into the United States, products that incorporate stacked semiconductor products and/or multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package, which are manufactured by Samsung and infringe one or more claims of the Elm 3DS Patents.

51. On information and belief, Samsung has designed, marketed and sold infringing products to third parties with knowledge and the specific intent to cause the third parties to in turn make, have made, use, sell, offer to sell in, and/or import into

the United States, products incorporating Samsung's stacked semiconductor products and/or multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package.

52. On information and belief, Samsung has designed its infringing products such that, as incorporated into the products of third parties, the third-party product infringes one or more claims of the Elm 3DS Patents if made, used, sold, offered for sale in, or imported into the United States.

53. On information and belief, Samsung is aware that by making, having made, using, selling, offering to sell in, or importing into the United States products that incorporate Samsung's infringing products, these third parties directly infringe one or more claims of the Elm 3DS Patents.

54. On information and belief, Samsung is aware that these third parties include, among many others, Apple, Dell, Intel, Amazon, Microsoft, and Google; and that products they make, have made, use, sell, offer to sell in, or import into the United States, include, among many others, SSD, server hardware, and mobile devices.

KNOWLEDGE OF PATENT EXISTENCE

55. Samsung has had actual knowledge of, or has been willfully blind to, the family of the Elm 3DS patents since 2000 or 2001. At that time, Mr. Leedy provided Samsung with a presentation on the Elm 3DS technology and sent a copy of the 5,915,167 patent. The '167 Patent is the parent patent in the Elm 3DS patent portfolio. At the very latest, Samsung has had actual notice of the Elm 3DS Patents and of its infringement as of the date of this Complaint.

KNOWLEDGE THAT THE INDUCED ACTS CONSTITUTE PATENT INFRINGEMENT

56. On information and belief, products sold or manufactured in the United States that incorporate Samsung's infringing stacked memory products include, but by no means are limited to, the Apple MacBook Pro, the Dell PowerEdge R920 server, the Intel Xeon E5-2600 v3 processor, the Amazon Fire Phone, the Amazon Kindle Fire HDX 7", the Microsoft Surface, and the Google Chromebook. These and other products incorporating Samsung's infringing products are currently offered for sale in the United States.

57. Samsung is aware that the products cannot be used or sold in a manner that does not infringe. Samsung is aware that the infringing stacked memory products are integral components of the computer and mobile products incorporating them, that the infringing stacked memory products are built into the computer and mobile products, and cannot be removed or disabled by a purchaser of the consumer products containing the infringing circuits. Therefore, Samsung is aware that its customers will infringe one or more claims of the Elm 3DS Patents by using the products as-sold and as-marketed by Samsung, and that subsequent sales of such products would be direct infringement.

58. On information and belief, Samsung also manufactures or sells products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another using TSV technology. Any OEM, manufacturer,

importer, reseller, customer, or and end user incorporating these products from Samsung directly infringes.

59. Samsung is aware that the products cannot be used or sold in a manner that does not infringe. Samsung is aware that the infringing memory products using TSV are integral components of the computer and mobile products incorporating them, that the infringing TSV products are built into the computer and mobile products, and cannot be removed or disabled by a purchaser of the consumer products containing the infringing circuits. Therefore, Samsung is aware that its customers will infringe one or more claims of the Elm 3DS Patents by using the products as-sold and as-marketed by Samsung, and that subsequent sales of such products would be direct infringement

SPECIFIC INTENT

60. Through its marketing of its infringing stacked semiconductor products, Samsung specifically intends for its customers, such as OEMs, manufacturers, importers, resellers, customers, and end users to purchase Samsung's stacked semiconductor products and to incorporate them into end products that directly infringe one or more claims of the Elm 3DS Patents. Samsung routinely markets its infringing stacked semiconductor products to third parties for inclusion in products that are sold to customers in the United States. For example, in its "Product Selection Guide" Samsung states that it "continues to lead the industry with the broadest portfolio of memory products and technology," including DRAM, flash NAND, and SSD products that are found in "ultra-mobile notebooks," "powerful servers," and a "wide range of handheld devices such as smartphones and tablets."

61. Samsung has a section of its website devoted to marketing its stacked semiconductor and TSV products to third parties for the purpose of incorporating said products into consumer or end-user devices that are made, have been made, used, offered for sale, sold, or imported into the United States. See <http://www.samsung.com/us/business/oem-solutions/index.html> (last accessed Nov. 20, 2014) (attached as Ex. 18.) This section of Samsung's website lists over thirty locations in the United States as part of Samsung's global "sales network." According to Samsung, "Samsung Semiconductor has a long standing presence in many of the world's major markets and has the best geographic coverage in the semiconductor industry." See <http://www.samsung.com/global/business/semiconductor/sales-network>. (last accessed Nov. 20, 2014) (attached as Ex. 19.)



You can find our **sales network**

Samsung Semiconductor has a long-standing presence in many of the world's major markets and has the best geographic coverage in the semiconductor industry

This sales network demonstrates Samsung's specific intent to induce infringement because it is established through Samsung's OEM division, which is intended to market

products to third-party manufacturers who sell electronics products in the United States.

62. As discussed above in Part IV, Samsung markets the benefits of its die-stacking technology. (*See, e.g., supra* ¶ 37.) By marketing its stacked memory products directly to third parties, Samsung is inducing them to infringe partly by showcasing the benefits of its die-stacking technology.

63. As a further example, Samsung states on its website that application processors such as the Exynos Octa-Widon, which incorporates TSV technology, are ideal for a wide variety of computing, communication and embedded devices, including mobile computing devices, mobile communications devices, entertainment/gaming devices, and consumer products. *See* Ex. 16.

64. Similarly, Samsung states on its website that stacked Flash NAND memory is used in a “a host of consumer, industrial, and automotive electronics” and that “Some of the principal areas that stand to benefit from using Samsung's packaging techniques for flash memory include” computing devices, buffers in hybrid drives, and removable storage media. *See* Ex. 11.

65. Samsung also recently announced on its website that its introduction of TSV-based DDR4 DRAM memory modules “will play a key role in supporting the continued proliferation of enterprise servers and cloud-based applications, as well as further diversification of data center solutions.” *See* Ex. 17.

66. On information and belief, Samsung has marketed its stacked semiconductor products for mobile phones specifically to third parties. Samsung has

promoted its “expertise in wafer thinning, die stacking, and wire bonding.” See <http://www.samsung.com/global/business/semiconductor/product/mcp/overview> (last accessed Nov. 20, 2014) (attached as Ex. 20.) Samsung markets these infringing products with the goal of including them in products that are sold in the United States. As evidenced by Samsung’s publicly available revenue figures, Samsung succeeds at this goal. These marketing activities demonstrate specific intent to induce infringement.

67. Samsung also provides OEMs, manufacturers, importers, resellers, customers, and end users instructions, user guides, and technical specifications on how to incorporate its infringing stacked semiconductor products into electronics products that are made, used, sold, offered for sale in and/or imported into the United States. When OEMs, manufacturers, importers, resellers, customers, and end users follow such instructions, user guides, and technical specifications and embed the stacked semiconductor products in end products they make, have made, use, offer to sell, sell, or import into the United States, they directly infringe one or more claims of the 3DS Patents. Samsung knows that by providing such instructions, user guides, and technical specifications, OEMs, manufacturers, importers, resellers, customers, and end users follow these instructions, user guides, and other technical specifications, and directly infringe one or more claims of the Elm 3DS Patents. Samsung thus knows that its actions actively induce infringement.

68. On information and belief, the targets for Samsung’s marketing efforts are OEMs or other manufacturers who then incorporate Samsung’s infringing stacked semiconductor products into electronics products that are made used, sold, offered for

sale in and/or imported into the United States. These marketing efforts demonstrate Samsung's attempts to induce infringement.

69. For example, at the 2014 Flash Memory Summit, in Santa Clara, California, Samsung showcased its latest memory technologies, in an effort to encourage various OEMs, manufacturers, importers, resellers, customers, and end users to include its infringing technology in computers, server hardware, and mobile devices. This event was attended by companies that make, have made, use, offer to sell, sell, or import in the United States products that use memory components such as those made and sold by Samsung. At the 2014 Flash Memory Summit Samsung made presentations touting the virtues of its memory products, including products that infringe one or more claims of the Elm 3DS Patents.

70. On information and belief, examples of third-party electronics products that incorporate Samsung's stacked semiconductor products include, but are not limited to the Apple MacBook Pro, Dell PowerEdge R920 server, the Intel Xeon E5-2600 v3 processor, the Amazon Fire Phone, the Amazon Kindle Fire HDX 7", the Microsoft Surface, and the Google Chromebook.

71. The specific products listed here are merely examples of the myriad products in which Samsung's infringing semiconductor products are incorporated. Samsung indirectly infringes the patents-in-suit by pursuing third-party customers for its products who then directly infringe by making, having made, using, offering to sell, selling, or importing in the United States products that infringe.

72. Samsung derives significant revenue by selling its stacked memory products to third parties who directly infringe one or more claims of the Elm 3DS Patents. For instance, Samsung derived sales of at least \$61 billion of semiconductors in 2012. Samsung also derived sales in the United States of products including semiconductors of at least \$86 billion in 2013.

73. Samsung's marketing efforts, press releases, sales volume, and partnerships all evidence its intent to induce companies to infringe one or more claims of the Elm 3DS Patents. Because Samsung has marketed its products to customers which it knows infringe one or more claims of the Elm 3DS Patents, it had the manifest specific intent to cause direct infringement and is therefore liable for indirect infringement. Given: (1) Samsung's knowledge that its stacked semiconductor products infringe one or more claims of the Elm 3DS Patents; (2) the volume of Samsung's stacked semiconductor sales within the United States; (3) Samsung's ubiquitous sales and marketing efforts directed to inducing third parties to include Samsung's stacked semiconductors in their products; (4) the fact that many third parties directly infringe one or more claims of the Elm 3DS Patents by making, having made, using, offering to sell, selling, or importing products that incorporate Samsung's stacked semiconductor products, Samsung has had specific intent to induce infringement or has been willfully blind to the direct infringement it is inducing.

74. The above-described acts of infringement committed by Defendants have caused injury and damage to Plaintiff, and will cause additional severe and irreparable injury and damages in the future.

FIRST CLAIM FOR RELIEF

Infringement of U.S. Patent No. 7,193,239

75. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

76. Defendants have directly infringed one or more claims of the Leedy '239 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

77. Defendants have indirectly infringed one or more claims of the Leedy '239 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another within a single chip package. The infringement remains ongoing.

78. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

SECOND CLAIM FOR RELIEF

Infringement of U.S. Patent No. 7,504,732

79. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

80. Defendants have directly infringed one or more claims of the Leedy '732 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

81. Defendants have indirectly infringed one or more claims of the Leedy '732 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package. The infringement remains ongoing.

82. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

THIRD CLAIM FOR RELIEF

Infringement of U.S. Patent No. 8,035,233

83. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

84. Defendants have directly infringed one or more claims of the Leedy '233 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

85. Defendants have indirectly infringed one or more claims of the Leedy '233 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package. The infringement remains ongoing.

86. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

FOURTH CLAIM FOR RELIEF

Infringement of U.S. Patent No. 8,410,617

87. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

88. Defendants have directly infringed one or more claims of the Leedy '617 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

89. Defendants have indirectly infringed one or more claims of the Leedy '617 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package. The infringement remains ongoing.

90. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

FIFTH CLAIM FOR RELIEF

Infringement of U.S. Patent No. 8,629,542

91. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

92. Defendants have directly infringed one or more claims of the Leedy '542 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

93. Defendants have indirectly infringed one or more claims of the Leedy '542 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another within a single chip package. The infringement remains ongoing.

94. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

SIXTH CLAIM FOR RELIEF

Infringement of U.S. Patent No. 8,653,672

95. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

96. Defendants have directly infringed one or more claims of the Leedy '672 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

97. Defendants have indirectly infringed one or more claims of the Leedy '672 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another within a single chip package. The infringement remains ongoing.

98. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

SEVENTH CLAIM FOR RELIEF

Infringement of U.S. Patent No. 8,796,862

99. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

100. Defendants have directly infringed one or more claims of the Leedy '862 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

101. Defendants have indirectly infringed one or more claims of the Leedy '862 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package. The infringement remains ongoing.

102. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

EIGHTH CLAIM FOR RELIEF

Infringement of U.S. Patent No. 8,824,159

103. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

104. Defendants have directly infringed one or more claims of the Leedy '159 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

105. Defendants have indirectly infringed one or more claims of the Leedy '159 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package. The infringement remains ongoing.

106. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

NINTH CLAIM FOR RELIEF

Infringement of U.S. Patent No. 8,841,778

107. Plaintiff incorporates by reference the allegations set forth in paragraphs 1 through 74 above as if specifically set forth herein.

108. Defendants have directly infringed one or more claims of the Leedy '778 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271. The infringing products include, but are not limited to, certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package, and Samsung electronics products that incorporate such chip packages. The infringement remains ongoing.

109. Defendants have indirectly infringed one or more claims of the Leedy '778 patent, literally and/or under the doctrine of equivalents, in violation of 35 U.S.C. § 271(b). The infringing products include third-party electronics products that incorporate certain of Samsung semiconductor products that incorporate multiple semiconductor die that are thinned, stacked on top of and electrically connected to one another through vertical interconnects within a single chip package. The infringement remains ongoing.

110. As a consequence of Defendants' infringement, Plaintiff is entitled to recover damages adequate to compensate it for the injuries complained of herein, but in no event less than a reasonable royalty.

JURY TRIAL DEMANDED

Elm 3DS Innovations, LLC, hereby demands a trial by jury on all claims and issues so triable.

PRAYER FOR RELIEF

WHEREFORE, Plaintiff respectfully requests that this Court:

- A. enter judgment that each of the Defendants has infringed one or more claims of one or more of the Elm 3DS Patents;
- B. enter an order, pursuant to 35 U.S.C. § 284, awarding to Plaintiff damages adequate to compensate for Defendants' infringement of the Elm 3DS Patents (and, if necessary, related accountings), in an amount to be determined at trial, but not less than a reasonable royalty;
- C. enter an order, pursuant to 35 U.S.C. § 285, deeming this to be an "exceptional case" and thereby awarding to Plaintiff its reasonable attorneys' fees, costs, and expenses;
- D. enter an order that Defendants account for and pay to Plaintiff the damages to which Plaintiff is entitled as a consequence of the infringement;
- E. enter an order awarding to Plaintiff pre- and post-judgment interest at the maximum rates allowable under the law; and
- F. enter an order awarding to Plaintiff such other and further relief, whether at law or in equity, that this Court deems just and proper.

DATED: November 21, 2014

Respectfully submitted,

FARNAN LLP

Of Counsel:

/s/ Brian E. Farnan

WILLIAM H. MANNING
SAMUEL L. WALLING
AARON R. FAHRENKROG
CHRISTINE YUN SAUER
MATTHEW J.M. PELIKAN
ROBINS, KAPLAN, MILLER & CIRESI L.L.P.
2800 LaSalle Plaza
800 LaSalle Avenue
Minneapolis, MN 55402-2015
Telephone: 612-349-8500
Facsimile: 612-339-4181
whmanning@rkmc.com
slwalling@rkmc.com
arfahrenkrog@rkmc.com
csyunsauer@rkmc.com
mjmpelikan@rkmc.com

JOSEPH J. FARNAN, JR. (Bar No. 100245)
BRIAN E. FARNAN (Bar No. 4089)
MICHAEL J. FARNAN (Bar No. 5165)
919 North Market Street, 12th Floor
Wilmington, Delaware 19801
(302) 777-0300
(302) 777-0301 (fax)
farnan@farnanlaw.com
bfarnan@farnanlaw.com
mfarnan@farnanlaw.com

Counsel for Elm 3DS Innovations, LLC